

UTC UNISONIC TECHNOLOGIES CO., LTD

Z00607

Preliminary

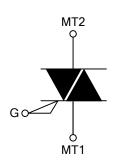
TRIAC

0.8A TRIACS

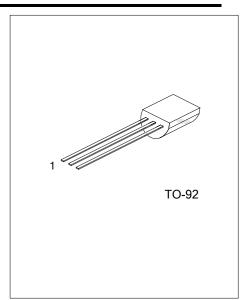
DESCRIPTION

The UTC Z00607 is a 0.8A triacs, it uses UTC's advanced technology to provide customers with low gate trigger current. The UTC Z00607 is suitable for low power AC switching

applications and driving microcontrollers.



SYMBOL



ORDERING INFORMATION

Ordering Number		Deekege	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
Z00607L-T92-B	Z00607G-T92-B	TO-92	MT1	GATE	MT2	Tape Box	
Z00607L-T92-K	Z00607G-T92-K	TO-92	MT1	GATE	MT2	Bulk	

Z00607 <u>Ģ-Т92</u> - <u></u>	
(1)Packing Type	(1) B: Tape Box, K: Bulk
(2)Package Type	(2) T92: TO-92
(3)Halogen Free	(3) G: Halogen Free, L: Lead Free

ABSOLUTE MAXIMUM RATINGS

PARAMETER			SYMBOL	RATINGS	UNIT	
Repetitive Peak Off-State Voltage			V _{DRM}	600	V	
RMS On-State Current (Full Sine Wave) T _{MB} =50		T _{MB} =50°C	I _{T(RMS)}	0.8	А	
Non Repetitive Surge Peak	F=50Hz	t=20ms		9		
On-State Current (Full Cycle, T _J initial=25°C)	F=60Hz	t=16.7ms	I _{TSM}	9.5	A	
I ² t Value for Fusing	t _P =10ms		I_t^2	0.45	A ² s	
Critical Rate of Rise of On-State Current I _G =2×I _{GT} , t _i ≤100ns	F=120Hz	TJ=110°C	dl/dt	20	A/µs	
Peak Gate Current	t _P =20µs	T _J =110°C	I _{GM}	1	А	
Average Gate Power Dissipation T _J =110°C		T _J =110°C	P _{G(AV)}	0.1	W	
Operating Junction Temperature Range		TJ	-40~+110	°C		
Storage Junction Temperature Range		T _{STG}	-40~+150	°C		

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Lead (AC)	θ_{JLEAD}	60	°C/W
Junction to Ambient	θ _{JA}	150	°C/W

■ ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS			TYP	MAX	UNIT
	I _{GT}		- -	MIN		5	
Gate Trigger Current (Note 1)		V _D =12V, R _L =30Ω	IV			7	mA
Gate Trigger Voltage	V _{GT}		ALL			1.3	V
Gate Non-Trigger Voltage	V_{GD}	V _D =V _{DRM} , R _L =3.3KΩ, T _J =110°C	ALL	0.2			V
Holding Current (Note 2)	Iн	I _T =200mA				5	mA
	١L	I _G =1.2I _{GT}	I-III-IV			10	
Latching Current			11			20	mA
Critical Rate of Rise of Off-State	a) //at	V _D =67%V _{DRM} , Gate Open, T _J =110°C		10			1////
Voltage (Note 2)	dV/dt			10			V/µs
Critical Rate of Rise of Off-State	(d) (/dt) a	(dV/dt)c=0.35A/ms, T _J =110°C		4 5			1///
Voltage at Commutation (Note 2)	(dV/dt)c			1.5			V/µs
Peak On-State Voltage (Note 2)	V _{TM}	I _{TM} =1.1A, t _p =380µs	TJ=25°C			1.5	V
Threshold Voltage (Note 2)	V _{TO}		TJ=110°C			0.95	V
Dynamic Resistance (Note 2)	RD		TJ=110°C			420	mΩ
Repetitive Peak Off-State Current	I _{DRM}	V _{DRM} =V _{RRM} =600V	TJ=25°C			5	μA
	I _{RRM}		T _J =110°C			0.1	mA

Notes: 1. Minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. For both polarities of MT2 referenced to MT1.



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